Observation of topological surface state in a superconducting material

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The discovery of topological insulator phase has ignited massive research interests in novel quantum materials. Topological insulators with superconductivity further invigorate the importance of materials providing the platform to study the interplay between these two unique states. However, the candidates of such materials are rare. Here, we report a systematic angle-resolved photoemission spectroscopy (ARPES) study of a superconducting material CaBi 2 [Tc = 2 K], corroborated by the first principles calculations. Our study reveals the presence of Dirac cones with a topological protection in this system. Systematic topological analysis based on symmetry indicator shows the presence of weak topological indices in this material. Furthermore, our transport measurements show the presence of large magnetoresistance in this compound. Our results indicate that CaBi 2 could potentially provide a material platform to study the interplay between superconductivity and topology.

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The advent of topological insulator (TI) brought a surge of research interests in the topological quantum materials [1–3]. Three dimensional (3D) topological insulators are non-trivial insulators in which bulk behaves as an insulator whereas the surface state behaves as a metal with spin-polarized electrons (non-degenerate spin state) dispersing linearly along the energy-momentum space. The characteristics of the topological insulators are governed by the surface state related to non-trivial topology protected by time-reversal symmetry [1, 2]. Topological insulators are characterized by Z2 invariants which distinguish strong and weak topological insulators from normal insulator. Strong topological insulators have an odd number of Dirac cones in a Brillouin zone, whereas weak topological insulators have an even number of Dirac cones in a Brillouin zone [1, 2]. The discovery of topological insulator invoked the domino effect in discovering the topological semimetals [1–4]. Broadly, 3D topological semimetals are categorized into Dirac semimetal [5, 6], Weyl semimetal [7–10] and nodal-line semimetal [11–15] featured by band-crossing, band-degeneracy and symmetry protection [15–17]. A 3D Dirac fermion is a massless fermion formed by the crossing of linearly dispersing bulk conduction and valence bands at the specific points in k-space, protected by inversion and time-reversal symmetry. On the other hand, the breaking of either of the symmetries provides the realization of Weyl semimetallic state. The Weyl nodes appearing in pairs with two fold degeneracies behave as the source and the sink of the berry phase in the k-space which are connected by the Fermi arc [3, 4, 17]. Similarly, if the linear band degeneracy persists along the line or ring instead of at discrete points, it is called a topological nodal-line semimetal [11, 18, 19].

Superconducting state in a topological material promises a possible route to realize the Majorana zero mode (MZM). Similar to other quasiparticles such as Dirac fermion and Weyl fermion, Majorana fermion - a quasiparticle which is the antiparticle of itself - exists in a condensed matter system [20, 21]. Realization of MZM is crucial for the development of quantum computers as it is anticipated to host qubit information [21]. Various roadmaps have been proposed in order to realize the Majorana zero mode (MZM) with some success consisting of strong spin-orbit coupled semiconductor nanowires [22], ferromagnetic atomic chain [23], proximity-induced topological superconductor [24–26]. However, a robust MZM which can be functional to device fabrication has not yet been realized due to complexities in the fabrications of the heterostructures [26]. Therefore, finding a superconducting topological material motivates current research interests.

Lately, tremendous efforts have been invested in order to realize the topological superconductors (TSC) believing it would be a transit to realize MZM. One promising route is to find a material having spin-triplet pairing state, which is commonly known as p-wave superconductor [21]. Cu-doped Bi2Se3, Sr2RuO4 are potential can-
FIG. 1: Crystal structure and sample characterization of CaBi$_2$. (a) Crystal structure of CaBi$_2$. (b) Projection of the 3D Brillouin zone onto the [010] surface, high symmetry points are labeled. (c) Resistivity as a function of temperature at the zero field and under 14 T field. (d) Magnetoresistance as a function of the magnetic field at various temperatures. (e) Inner core spectra shows the peaks for Bi 5$d$ indicating Bi termination. (f) First principles calculations of the bulk band of CaBi$_2$. (g) Slab calculation of CaBi$_2$ along the M-X-M direction.

didates of this category [27, 28]. Another sturdy route to realize TSC is the s-wave superconductivity in a spin-polarized state. Some evidences of such systems have been observed, which have strong $\mathbb{Z}_2$ index [29, 30]. Recently, large pool of materials with topological insulating state have been discovered, which are defined beyond Fune-Kane criterion using different symmetry settings [31–34]. The interplay between the superconductivity and topology in these type of novel TI is yet to be established, which provides a new avenue for the research interests.

In this communication, we report the electronic band structure of superconducting CaBi$_2$ using angle-resolved photoemission spectroscopy and complemented by first principles calculations. Our study reveals the presence of Dirac state in CaBi$_2$ at the corner point (X) in the Brillouin zone. Our calculations show the existence of topological insulating state which is embedded within the bulk bands and symmetry indicator analysis also bolsters the existence of weak topological insulator. Furthermore, this compound demonstrates the large-magnetoresistance indicating topologically non-trivial state.

The single crystals of the CaBi$_2$ were grown and characterized (X-ray diffraction, energy-dispersive X-ray spectroscopy, electrical resistivity, magnetoresistance) as described in Supplemental Material [35]. Synchrotron based ARPES measurements were performed at the Advanced Light Source (ALS), Berkeley at Beamline 4.0.3 equipped with a high efficiency R8000 electron analyzer. The energy resolution was better than 20 meV and the angular resolution was better than 0.2°. Samples were prepared inside a glove box in order to avoid decomposition of the samples. The samples were cleaved in situ and measured between 10 - 80 K in a vacuum better than $10^{-10}$ torr. The cleavage plane of single-crystalline CaBi$_2$ was the [010] plane. These crystals were found to be very stable without surface degradation for the typical measurement period of 20 hours. In order to reveal the nature of the states observed in CaBi$_2$, the ARPES data were compared with the calculated band dispersion projected onto a 2D Brillouin zone (BZ). For our first-principles calculations, the WIEN2k package [36] was used (for detailed information see method section in supplemental material [35]).

We begin our discussion with the crystal structure of the CaBi$_2$. The powdered X-ray diffraction pattern depicts that CaBi$_2$ crystallizes in an orthorhombic lattice, as shown in Fig. 1(a), with non-symmorphic symmetry group $\text{Cmcm}$ (No. 63) [37, 38]. The crystal structure has quasi-two-dimensional characters, and can be viewed as stacking of a square planar lattice of Bi(1) and a corrugated square lattice of Ca and Bi(2), with the nodes of
FIG. 2: Measured Fermi surface and constant energy contours. (a) Fermi surface map at a photon energy of 90 eV. High symmetry points are labeled on the plot. (b)-(d) Constant energy contours at different binding energies. Binding energies are noted on the top of each panels. Dotted rectangle serves as a guide to eyes to visualize the Dirac node.

one lattice positioned above the centers of the squares of the other lattice [37]. The lattice parameters are obtained to be \(a=4.696(1) \, \text{Å}, b=17.081(2) \, \text{Å}, \) and \(c=4.611(1) \, \text{Å}\) which are consistent with previous reports [37, 38]. The crystals, on which we performed experiments, are flat, shiny and layered, with natural cleaving plane of [010]. Therefore, in Fig. 1(b) we present the projection of the 3D Brillouin zone onto [010] surface transforming into a rectangular 2D Brillouin zone.

As extensively shown in Ref. [37], single-crystalline CaBi\(_2\) exhibits type-I moderately-coupled superconductivity that emerges below the critical temperature \(T_c = 2.0\, \text{K}\). Fig. 1(c) presents the temperature dependence of the electrical resistivity measured in the normal state of the very same sample that was investigated in Ref. [37]. The experiment was performed with electrical current flowing within the a-c plane of the orthorhombic unit cell. The compound exhibits metallic behavior with the resistivity decreasing in a smooth manner from about 74 m\(\Omega\)cm at room temperature down to 0.3 m\(\Omega\)cm at 2 K. Very small magnitude of the residual resistivity as well as large ratio between the values measured at 300 K and 2 K prove that CaBi\(_2\) is a very good electrical conductor.

Upon applying magnetic field of 14 T, directed perpendicular to the electrical current, the resistivity of CaBi\(_2\) becomes a non-monotonous function of temperature, namely \(\rho(T)\) exhibits an upturn below about 30 K and then forms a plateau at the lowest temperatures. Fig. 1(d) presents the transverse magnetoresistance MR = \(\rho(T,H) - \rho(T,0)/\rho(T,0)\) measured as a function of magnetic field at several temperatures up to 50 K. Remarkably, the isotherms taken at 2 K and 5 K, i.e. in the resistivity plateau region, show a nonsaturating behavior with huge values of about 7000-6000 \% in a magnetic field of 14 T. At higher temperatures, the magnitude of MR rapidly decreases; in the same field, its only about half that value at \(T = 10\, \text{K}\), and below 300 \% at \(T = 20\, \text{K}\). At the highest temperature studied, i.e. 50 K, MR in 14 T drops below 100 \%.

Remarkably, very similar behavior of the transverse magnetotransport has been reported for topologically nontrivial semimetals, like WTe\(_2\) [39], TaAs\(_2\) [40] or NbSb\(_2\) [41], and interpreted either as magnetic-field-driven metal-insulator transition in Dirac systems or an effect of magnetic-field-induced changes in charge carrier densities and mobilities in almost perfectly electron-hole compensated semimetals. It is also worth noting that the magnetoelectrical properties of CaBi\(_2\) are also very similar to those found for the widely studied nodal-line topological semimetal ZrSIS [42, 43]. The core level spectrum displayed in Fig. 1(e) indicates the sharp Bi 5d peaks of the cleaved sample. Our band structure calculations for
the bulk CaBi$_2$ (see Fig. 1(f)) show three energy bands crossing the Fermi level along the Y-T direction, suggesting a metallic behavior. However, it is also evident that there is a continuous band gap open between the two energy bands near the Fermi level. We used the vasp2trace code and CaBi$_2$ is found to be a topological insulator with topological indices $Z_{2w,3} = 0$, $Z_4 = 0$, $Z_{2w,1} = 1$, $Z_{2w,2} = 1$ (see supplemental material for details and related references [35]). For the symmetry group 63, topological indices $Z_1$ and $Z_{2w,1=1,2,3}$ identify the strong or weak TI. The odd value of former gives the strong TI whereas latter gives the weak TI [33]. Therefore, on the basis of calculation, we can categorize CaBi$_2$ as a weak TI.

We present slab calculations along the M-X-M direction. Our theoretical calculations show electron-like bands existing at the X point surrounded by the hole like bands. Furthermore, slab calculations show the bands are enriched with the bulk originations. The linear bands we see in the experiments should be buried within the bulk bands. Our calculations show that the bands-inversion takes place at the S point of the bulk Brillouin zone, which projects to the X point on the surface BZ, indicating topological surface state exists at the X point. This system holds an even number of Dirac cones per Brillouin zone which further confirms the weak TI state in CaBi$_2$.

We present ARPES measured electronic structures of CaBi$_2$ in Fig. 2. Fermi surface map and constant energy contours show the band structure evolution with the binding energy. The Fermi surface map reveals the multiple band crossings at the Fermi level which can be seen by multiple Fermi pockets shown in Fig. 2(a). The spectral intensities of BZs appear unequal because of the matrix element effects, however, the symmetric patterns are well resolved. The Fermi surface exhibits a diamond-shaped Brillouin zone similar to the ZrSiS system [14]. The diamond-shaped Fermi surfaces are intertwined with other Fermi pockets. Bands are absent at the zone center ($\Gamma$), which lies at the center of the diamond-like feature. The M point makes the center of the diamond shaped feature existing between the Brillouin zones. These two diamond-like features in an extended Brillouin zone make an impression of alternatively changing tile patterns on the floor. Presented constant energy contours indicate the presence of the Dirac state showing a Dirac node located at the binding energy of 530 meV (see Fig. 3 to visualize the Dirac states in different binding energies at the corner point (X)). A dotted rectangle is drawn in Fig. 2(d) to depict the Dirac node. Figure 2(b)-(c) show the energy contours at the binding energy of 200 meV and 500 meV respectively showing the evolution of Dirac cone with the binding energy. At the X point, an electron like band can be seen. The energy contours clearly show that hole like bands exist around the $\Gamma$ point, whereas, the M point consists of electron like bands.

In order to understand the nature of the Dirac states in the vicinity of the X point, we present dispersion maps along the M-X-M direction which reveals the presence of a linearly dispersive bands state. Linear bands, which cross the Fermi level near to the X point, propagate along the M-X direction. The potential band crossing between these bands are not accessible to the ARPES measurements due to its location above the Fermi level. We present a second derivative plot of the intensity map in Fig. 3(b) which conspicuously shows the presence of linear bands and Dirac crossings. In order to gather an information regarding the surface nature of the bands along the M-X-M direction, we provide photon energy dependent dispersion maps in Fig. 3(c). The photon energy dependent measurements indicate the surface nature of the Dirac cones. We present dispersion maps along different symmetry directions in the Supplemental Material [35].

Landau-Ginzburg-Wilson framework of spontaneous symmetry breaking provides the explanation to the exotic phenomena such as superconductivity, magnetism etc [44]. Even though topological systems are beyond this paradigm, the role of the symmetries still plays a guiding role. Fu-Kane criterion has been well established for distinguishing the topological insulators from trivial insulator. $Z_2$ ($\nu_0; \nu_1, \nu_2, \nu_3$) indices define topological indices based on Fu-Kane criterion [31]. Odd value of $\nu_0$ indicates strong TI whereas the odd value of either of $\nu_{1,2,3}$ indicates the weak TI. Recently, symmetry indicators (SI) have expanded beyond Fu-Kane model [31, 33, 34] in order to identify topological materials for different symmetry groups. Fu-Kane criterion segregates TI state from trivial state on the basis of parity eigenvalues whereas new criterion use symmetry indicators to classify materials. This new criterion has incorporated large number of materials in TI category providing an opportunity to identify the large number of TI, CaBi$_2$ falls under this category of the materials which cannot be distinguished by $Z_2$ indices alone. The existence of superconductivity in this compound provides us new dimension and perspective. Due to the strong hybridization among the bands, the surface states are masked by the bulk bands. Therefore, in first-principles calculations the surface states are embedded in bulk bands. Being a unique superconducting material from the Ca-Bi family, this stoichiometry is a crucial compound of this family. Furthermore, this binary superconductor has high magnetoresistance which is an indication of topologically non-trivial state in this material.

In conclusion, our ARPES measurements and first principles calculations reveal the weak topologically protected surface state in a superconducting material CaBi$_2$. The surface state is observed at the X point of the Brillouin zone. The symmetry analysis reveals new class of topological insulating state in CaBi$_2$. Our transport measurements shows high magnetoresistance possibly arising from non-trivial state. Our systematic could study potentially provide a new route to study the interplay be-
tween superconductivity and topology.

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